

Listing of Claims

Please cancel claims 47, 48, 57, 58, 61, 64, 68, 69 and 74-87 without prejudice.

The status of the claims of the case are as follows:

Claims 1-39 (canceled)

D
~~40~~ (previously presented) A catalyst having activity under an irradiation of visible light in a wavelength region from about 400 to 600 nm, comprising titanium dioxide having stable oxygen defects and exhibiting NO_x oxidation activity under the irradiation of a visible light at least in the wavelength region of from about 400 to 600 nm; and said titanium dioxide further having a peak area ratio (O1s/Ti2p) of a peak area obtained by X-ray photoelectron spectroscopy assigned to the 1s electrons of oxygen (O1s) participating in the bonds with titanium to a peak area obtained by X-ray photoelectron spectroscopy assigned to the 2p electrons of titanium (Ti2p) of 1.99 or lower.

~~41~~ (previously presented) The catalyst according to claim ~~40~~, wherein said titanium dioxide component comprises titanium dioxide of an anatase type or a rutile type.

~~42~~ (previously presented) The catalyst according to claim ~~40~~, wherein the titanium dioxide has a primary particle size of 10 nm or less in diameter.

~~43~~ (previously presented) The catalyst according to Claim ~~40~~, comprising titanium dioxide that is characterized by an X-ray diffraction (XRD) pattern that is substantially free from patterns other than patterns assigned to anatase type titanium dioxide.

²⁸
~~44~~ (previously presented) A catalyst having activity under an irradiation of visible light, said catalyst comprising titanium dioxide having stable oxygen defects and a peak area ratio (O1s/Ti2p) of a peak area obtained by X-ray photoelectron spectroscopy assigned to the 1s electrons of oxygen (O1s) participating in the bonds with titanium to a peak area obtained by X-ray photoelectron spectroscopy assigned to the 2p electrons of titanium (Ti2p) of 1.99 or lower.

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~~45~~ (previously presented) The catalyst according to claim ⁸~~44~~, wherein said peak area ratio (O1s/Ti2p) is in a range of from 1.5 to 1.95.

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~~46~~ (previously presented) The catalyst according to claim ⁸~~44~~, wherein said peak area ratio (O1s/Ti2p) remains substantially constant for time durations of 1 week or longer.

Claims 47-49 (canceled)

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~~50~~ (previously presented) A method for producing a catalyst comprising titanium dioxide having stable oxygen defects and a ratio of a peak area obtained by X-ray photoelectron spectroscopy assigned to the 1s electrons of oxygen participating in the bonds with titanium to a peak area obtained by X-ray photoelectron spectroscopy assigned to the 2p electrons of titanium (O1s/Ti2p) of 1.99 or lower and having activity under an irradiation of a visible light, said method comprising treating the titanium dioxide with hydrogen plasma, characterized by performing said treatment in a state substantially free from an intrusion of air into a treatment system.

113 31.14
50. (previously presented) The method for producing a catalyst according to claim 50, wherein said treatment is performed in a tightly sealed system and said state substantially free from the intrusion of air into the treatment system is a state in which a vacuum degree inside the tightly sealed system takes at least 10 minutes to make a change of 1 Torr.

113 32.15
50. (previously presented) The method for producing a catalyst according to claim 50, wherein said oxide semiconductor is selected from the group consisting of titanium dioxide, zirconium oxide, hafnium oxide, strontium titanate, a titanium oxide-zirconium oxide based complex oxide, and a silicon oxide-titanium oxide based complex oxide.

P 119 33.19
50. (previously presented) A method for producing a catalyst comprising titanium dioxide having stable oxygen defects and a ratio of a peak area obtained by X-ray photoelectron spectroscopy assigned to the 1s electrons of oxygen participating in the bonds with titanium to a peak area obtained by X-ray photoelectron spectroscopy assigned to the 2p electrons of titanium (O1s/Ti2p) of 1.99 or lower and having activity under an irradiation of a visible light, said method comprising treating the titanium dioxide with a plasma of rare gas, and performing said treatment in a state substantially free from an intrusion of air into a treatment system.

119 34.20
50. (previously presented) The method for producing a catalyst according to claim 50, wherein said state substantially free from the intrusion of air into the treatment system is a state in which a vacuum degree inside a tightly sealed system takes at least 10 minutes to make a change of 1 Torr.

19 35. (previously presented) The method for producing a catalyst according to claim 33, wherein said oxide semiconductor is selected from the group consisting of titanium dioxide, zirconium oxide, hafnium oxide, strontium titanate, a titanium oxide-zirconium oxide based complex oxide, and a silicon oxide-titanium oxide based complex oxide.

36. (previously presented) A method for producing a catalyst comprising titanium dioxide having stable oxygen defects and a ratio of a peak area obtained by X-ray photoelectron spectroscopy assigned to the 1s electrons of oxygen participating in the bonds with titanium to a peak area obtained by X-ray photoelectron spectroscopy assigned to the 2p electrons of titanium (O1s/Ti2p) of 1.99 or lower and having activity under an irradiation of visible light, comprising the step of introducing ions of a rare gas on at least a portion of the surface of the titanium dioxide by means of ion implantation.

Claims 57-58 (canceled)

13 39. (previously presented) The method for producing a catalyst according to Claim 50, wherein said oxide semiconductor is an anatase type titanium dioxide.

19 40. (previously presented) The method for producing a catalyst according to Claim 53, wherein said oxide semiconductor is an anatase type titanium dioxide.

Claim 61 (canceled)

41 42. (previously presented) A catalyst produced by the method of Claim 50 and having activity under the irradiation of a visible light.

~~63~~⁷³ (previously presented) A catalyst produced by the method of Claim ~~33~~¹⁹
and having activity under the irradiation of a visible light.

Claim 64 (canceled)

~~65~~¹¹⁸ (previously presented) The catalyst according to Claim ~~62~~¹⁷, wherein said
oxide semiconductor is titanium dioxide, zirconium oxide, hafnium oxide, strontium titanate, a
titanium oxide-zirconium oxide based complex oxide, or a silicon oxide-titanium oxide based
complex oxide.

~~66~~¹²⁴ (previously presented) The catalyst according to Claim ~~63~~⁷³, wherein said
oxide semiconductor is titanium dioxide, zirconium oxide, hafnium oxide, strontium titanate, a
titanium oxide-zirconium oxide based complex oxide, or a silicon oxide-titanium oxide based
complex oxide.

~~67~~¹¹ (previously presented) The catalyst according to Claim ~~44~~⁸, wherein said
activity under the irradiation of visible light is an oxidation activity or a reduction activity.

Claims 68-69 (canceled)

~~70~~¹¹² (previously presented) The catalyst according to Claim ~~44~~⁹, wherein said
activity under the irradiation of visible light is a decomposition activity for inorganic and organic
substances, or a bactericidal activity.

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~~71~~ (previously presented) The catalyst according to claim ~~40~~¹, wherein said catalyst is in a substantially granular, thin-film, or sheet shape.

~~72~~⁴ (previously presented) The catalyst of claim ~~40~~¹, wherein said catalyst material has been provided on the surface of a base material substrate.

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~~73~~⁷ (previously presented) The catalyst article according to Claim ~~72~~⁶, wherein said base material is an exterior wall of a building, an exterior plane of a roof or a ceiling, an outer plane or an inner plane of a window glass, an interior wall of a room, a floor or a ceiling, a blind, a curtain, a protective wall of highway roads, an inner wall inside a tunnel, an outer plane or a reflective plane of an illuminating light, an interior surface of a vehicle, or a plane of a mirror.

Claims 74-87 (canceled)

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